

**100V NPN MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223**
**Features**

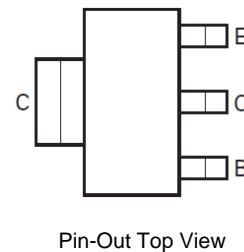
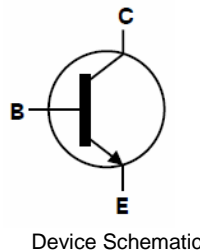
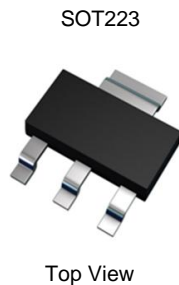
- $BV_{CEO} > 100V$
- $I_C = 5.5A$  Continuous Collector Current
- $I_{CM} = 10A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < 65mV @ 1A$
- $R_{SAT} = 43m\Omega @ I_C = 6A$  for Low Equivalent On-Resistance
- $h_{FE}$  Specified up to 5.5A for High Gain Hold Up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.  
UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads.  
Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.112 grams (Approximate)

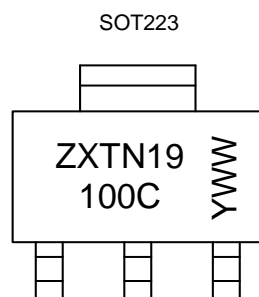
**Applications**

- Line Switching
- Motor Driving (including DC fans)
- High-Side Switches
- Subscriber Line Interface Cards (SLIC)


**Ordering Information** (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN19100CGTA	ZXTN19100C	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


ZXTN19 100C = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 5= 2015)  
 WW or  $\bar{W}W$  = Week Code (01-53)

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	200	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	I <sub>C</sub>	5.5	A
Peak Pulse Current	I <sub>CM</sub>	10	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

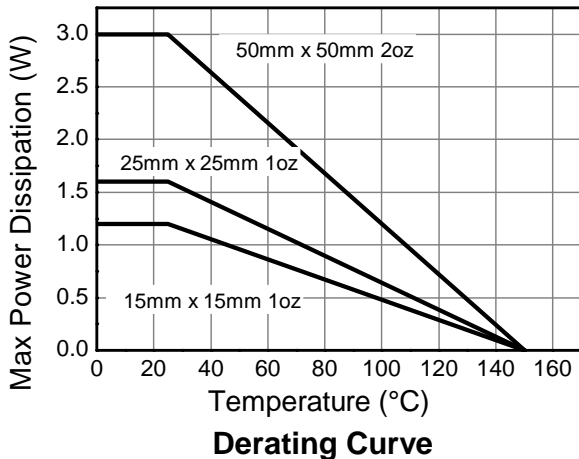
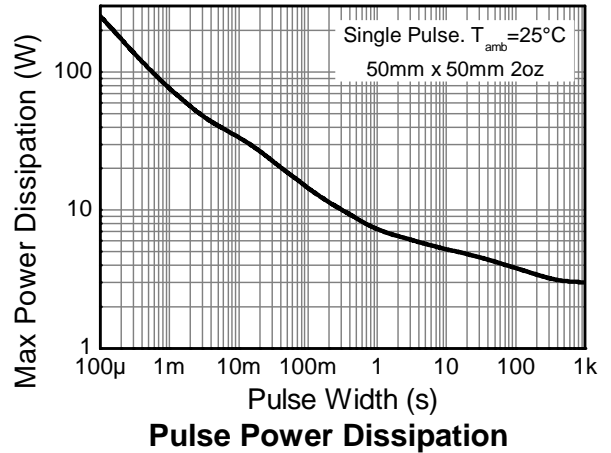
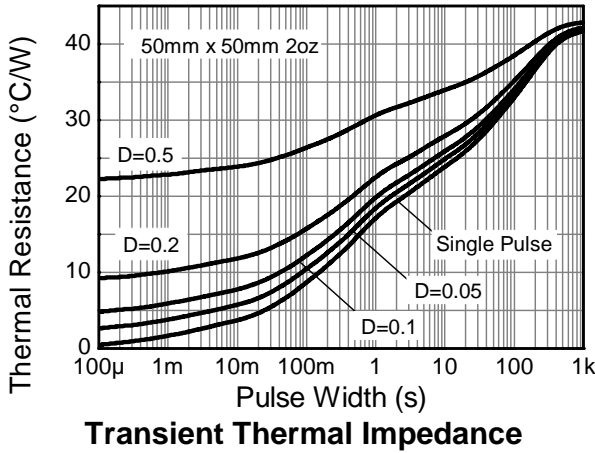
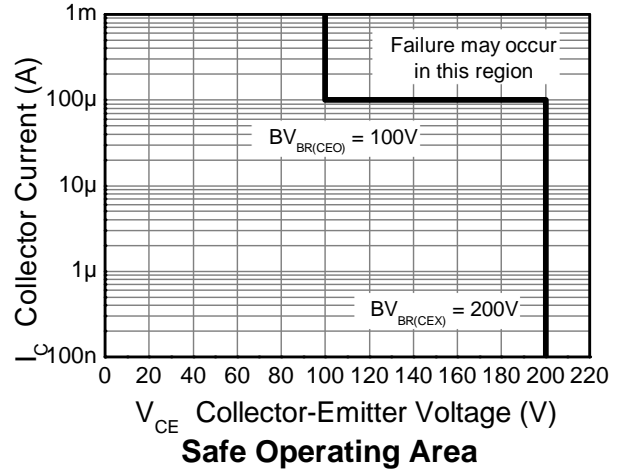
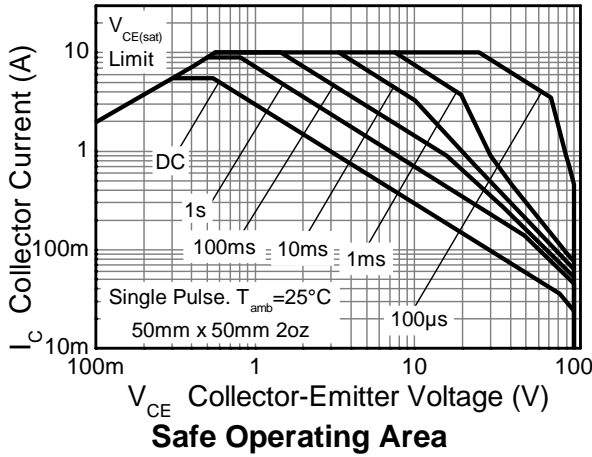
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P <sub>D</sub>	3.0	W mW/°C
		24	
		1.6	
		12.8	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	42	°C/W
	R <sub>θJA</sub>	78	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	8.8	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz. copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
  6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

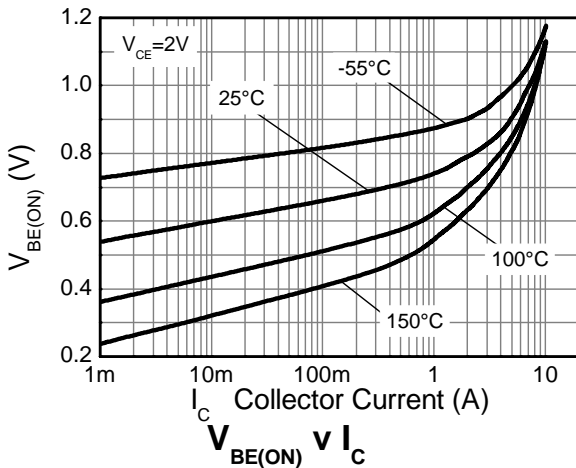
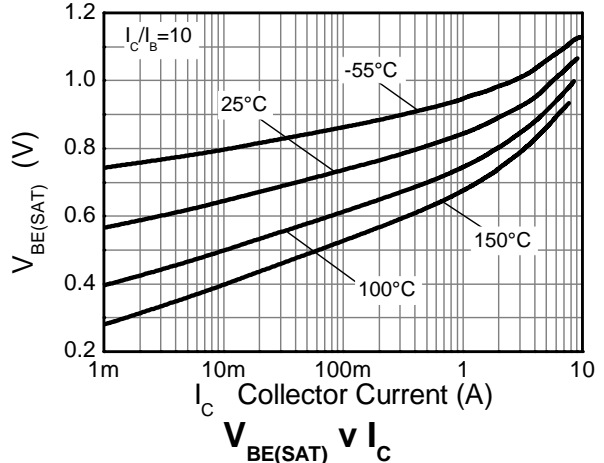
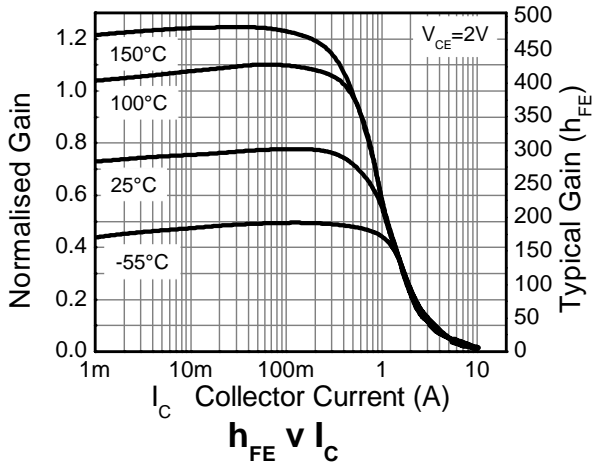
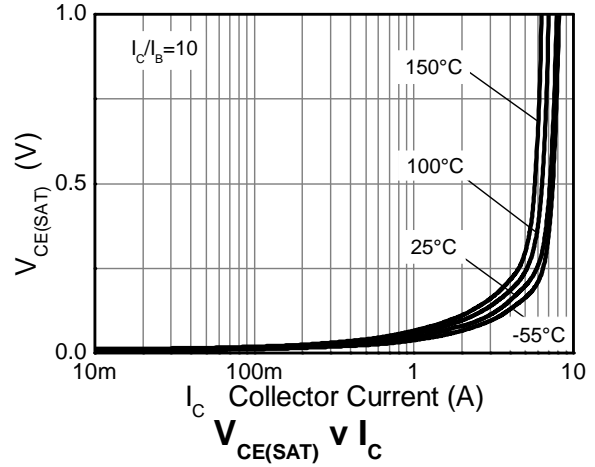
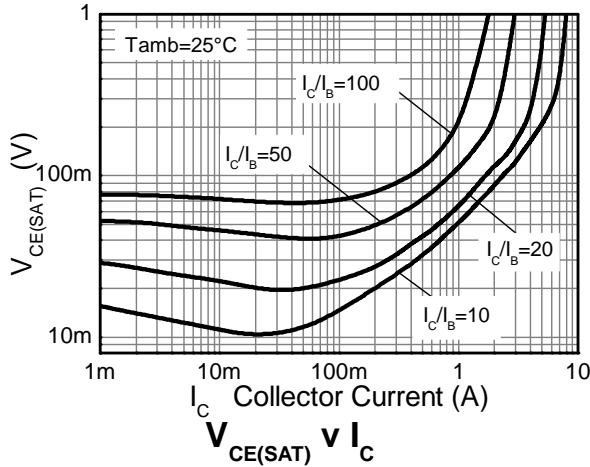


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	200	240	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	100	120	—	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>ECO</sub>	5	8	—	V	I <sub>E</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	—	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	—	<1	50	nA	V <sub>CB</sub> = 200V
Collector Cutoff Current	I <sub>CEX</sub>	—	—	100	nA	V <sub>CB</sub> = 200V, R <sub>BE</sub> < 1kΩ
Emitter Cutoff Current	I <sub>EBO</sub>	—	<1	50	nA	V <sub>EB</sub> = 5.6V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	—	50 110 245	65 140 430	mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA I <sub>C</sub> = 1A, I <sub>B</sub> = 20mA I <sub>C</sub> = 5.5A, I <sub>B</sub> = 550mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	1.005	1.1	V	I <sub>C</sub> = 5.5A, I <sub>B</sub> = 550mA
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	—	0.95	1.05	V	I <sub>C</sub> = 5.5A, V <sub>CE</sub> = 2V
DC Current Gain (Note 9)	h <sub>FE</sub>	200 130	300 190 25	500		I <sub>C</sub> = 100mA, V <sub>CE</sub> = 2V I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V I <sub>C</sub> = 5.5A, V <sub>CE</sub> = 2V
Transition Frequency	f <sub>T</sub>	—	150	—	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 50MHz
Input Capacitance	C <sub>IBO</sub>	—	305	400	pF	V <sub>EB</sub> = 0.5V, f = 1MHz
Output Capacitance (Note 9)	C <sub>OBO</sub>	—	15.7	25	pF	V <sub>CB</sub> = 10V, f = 1MHz
Switching Times	t <sub>ON</sub>	—	51.9	—	ns	V <sub>CC</sub> = 10V, I <sub>C</sub> = 500mA, I <sub>B1</sub> = -I <sub>B2</sub> = 50mA
	t <sub>OFF</sub>	—	1,095	—		

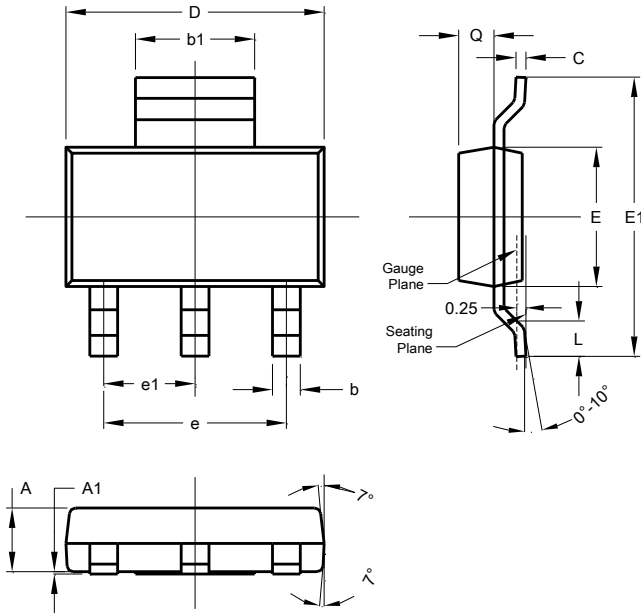
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Package Outline Dimensions**

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

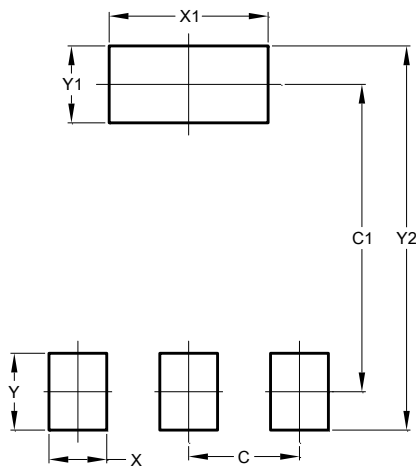


SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89

All Dimensions in mm

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
C2	8.00

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